

Advance Technical Information

PolarHV[™] IGBT

IXGH28N60B3D1





Symbol	Test Conditions	Maximum Ratings			
V _{CES}	$T_{J} = 25^{\circ}C \text{ to } 150^{\circ}C$	600	V		
V _{CGR}	$T_{J} = 25^{\circ}C$ to 150°C, $R_{GE} = 1M\Omega$	600	V		
V _{ges}	Continuous	± 20	V		
V _{GEM}	Transient	± 30	V		
I _{C25}	$T_c = 25^{\circ}C$	66	A		
I _{C110}	$T_c = 110^{\circ}C$	28	А		
I _{F110}	$T_c = 110^{\circ}C$	10	А		
I _{CM}	$T_c = 25^{\circ}C$, 1ms	150	A		
SSOA (RBSOA)	V_{ge} = 15V, T_{VJ} = 125°C, R_{g} = 10 Ω Clamped inductive load @ \leq 600V	I _{CM} = 60	A		
P _c	$T_c = 25^{\circ}C$	190	W		
T,		-55 +150	°C		
Т _{јм}		150	°C		
T _{stg}		-55 +150	°C		
T _l T _{sold}	1.6mm (0.062 in.) from case for 10 seconds Plastic body for 10 seconds	300 260	°C ℃		
M _d	Mounting torque (M3)	1.13/10	Nm/lb.in.		
Weight		6	g		

Symbol (T _J = 25°C	Test Conditions unless otherwise specified)	Cha Min.	Characteristic Va Min. Typ. M		
BV _{CES}	I _c = 250μA, V _{GE} = 0V	600			V
V _{GE(th)}	$I_c = 250 \mu A$, $V_{ce} = V_{ge}$	3.0		5.0	V
I _{CES}	$V_{CE} = V_{CES} V_{GE} = 0V$ $T_{J} = 125^{\circ}C$	2		50 1.0	μA mA
I _{GES}	$V_{_{CE}}$ = 0V, $V_{_{GE}}$ = ± 20V			±100	nA
V _{CE(sat)}	I _c = 24A, V _{GE} = 15V, Note 1		1.5	1.8	V

TO-247 (IXGH)



G = Gate	C = Collector
E = Emitter	TAB = Collector

Features

- Square RBSOA
- High current handling capability
- MOS Gate turn-on
 - drive simplicity

Applications

- PFC circuits
- Uninterruptible power supplies (UPS)
- Switched-mode and resonant-mode power supplies
- AC motor speed control
- DC servo and robot drives
- DC choppers

LIXYS

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SymbolTest Conditions $(T_J = 25^{\circ}C, unless otherwise specified)$					
g_{fs} $I_{c} = I_{C110}, V_{CE} = 10V, Note 1$	18	30	s		
C _{ies}		2320	pF		
C_{oes} $V_{CE} = 25V, V_{GE} = 0V, f = 1MHz$		176	pF		
C _{res}		24	pF		
Q _a)		62	nC		
Q_{ge} $I_{C} = I_{C110}, V_{GE} = 15V, V_{CE} = 0.5 \bullet V_{OE}$	CES	11	nC		
Q _{gc}		23	nC		
t _{d(on)}		19	ns		
t		24	ns		
E_{on} Inductive load, $T_{J} = 25^{\circ}C$		0.34	mJ		
$I_c = 24A, V_{GE} = 15V$ $I_d(off)$ $V_c = 400V R = 100$		125	200 ns		
t_{fi} V _{CE} = 400V, R _G = 10Ω		100	160 ns		
E _{off}		0.65	1.2 mJ		
t _{d(on)}		19	ns		
t.		26	ns		
\mathbf{E}_{on} Inductive load, $\mathbf{T}_{J} = 125^{\circ}\mathbf{C}$		0.6	mJ		
$I_{c} = 24A, V_{GE} = 15V$		180	ns		
t_{fi} $V_{CE} = 400V, R_G = 10\Omega$		170	ns		
E _{off}		1.0	mJ		
R _{thJC}			0.66 °C/W		
R _{thCS}		0.21	°C/W		



Reverse Diode (FRED)

		Characteristic Values Min. Typ. Max.			
V _F	$I_{F} = 24A, V_{GE} = 0V, \text{ Note 1}$ $T_{J} = 150^{\circ}\text{C}$		2.5 V 1.7 V		
I _{RM}	$\begin{cases} I_{_{\rm F}} &= 24A, V_{_{\rm GE}} = 0V, -di_{_{\rm F}}/dt = 100A/\mu s \\ V_{_{\rm R}} &= 100V \end{cases}$	5	A		
t _{rr}	$I_{\rm F} = 1$ A, $-di_{\rm F}/dt = 100$ A/µs, $V_{\rm R} = 30$ V	25	ns		
) T _J = 100°C	100	ns		
$R_{_{thJ}}$			1.0 K/W		

Note 1: Pulse test, t \leq 300 $\mu s;$ duty cycle, d \leq 2%.

ADVANCE TECHNICAL INFORMATION

The product presented herein is under development. The Technical Specifications offered are derived from a subjective evaluation of the design, based upon prior knowledge and experience, and constitute a "considered reflection" of the anticipated result. IXYS reserves the right to change limits, test conditions, and dimensions without notice.

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IXYS MOSFETs and IGBTs are covered	4,835,592	4,931,844	5,049,961	5,237,481	6,162,665	6,404,065 B1	6,683,344	6,727,585	7,005,734 B2	7,157,338B2
by one or moreof the following U.S. patents:	4,850,072	5,017,508	5,063,307	5,381,025	6,259,123 B1	6,534,343	6,710,405 B2	6,759,692	7,063,975 B2	
	4,881,106	5,034,796	5,187,117	5,486,715	6,306,728 B1	6,583,505	6,710,463	6,771,478 B2 7,071,537		



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